



2SK3335

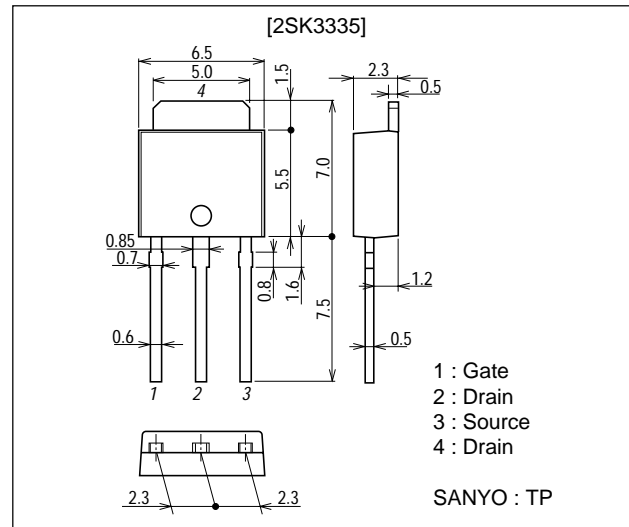
Ultrahigh-Speed Switching Applications

Features

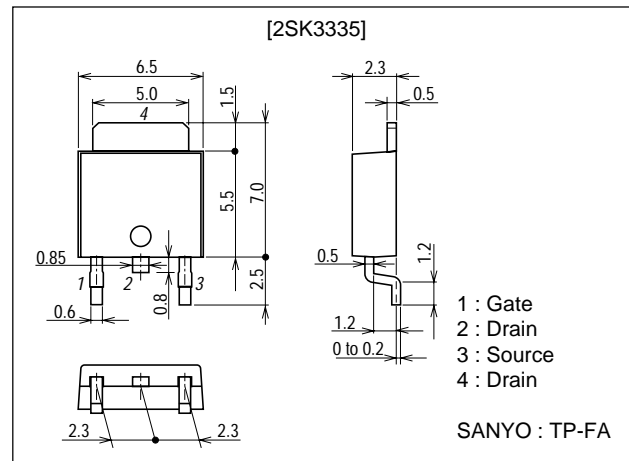
- Low ON-resistance.
- 4V drive.

Package Dimensions

unit : mm
2083B



unit : mm
2092B



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Specifications

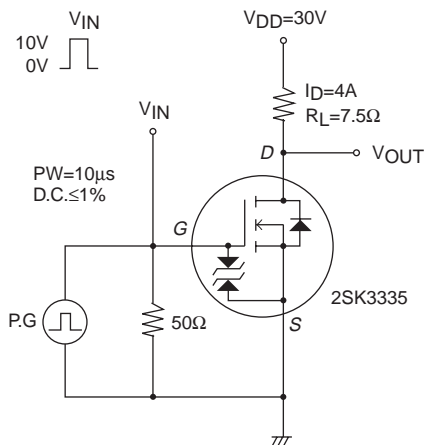
Absolute Maximum Ratings at Ta=25°C

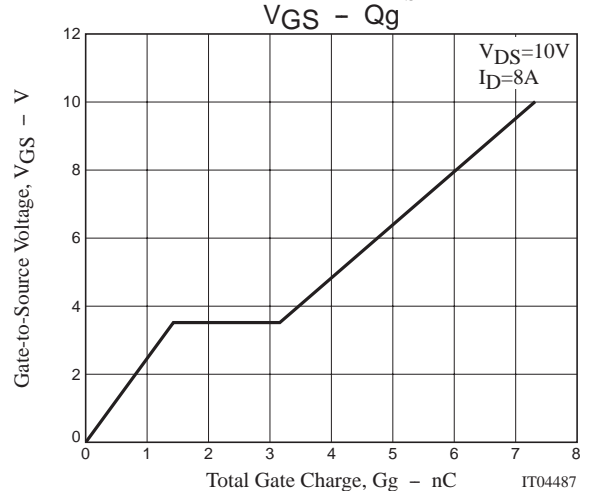
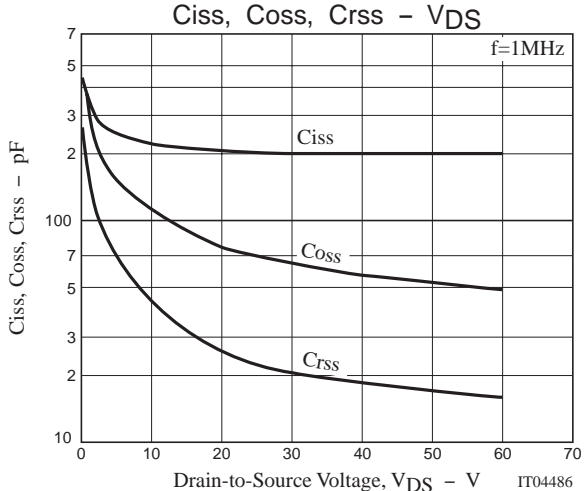
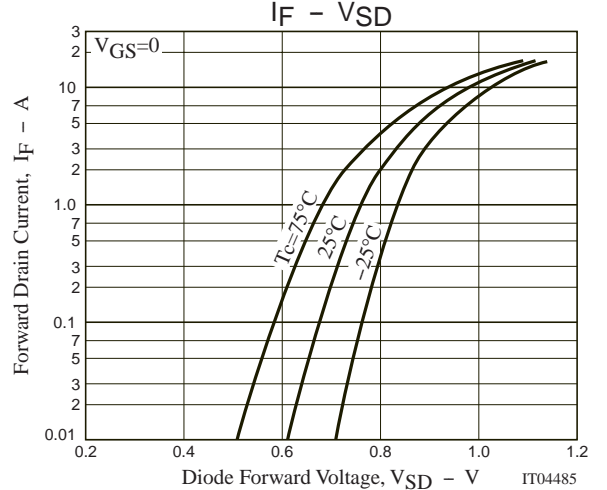
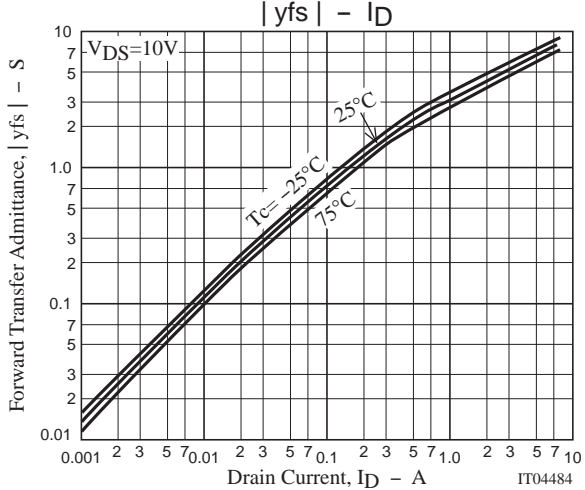
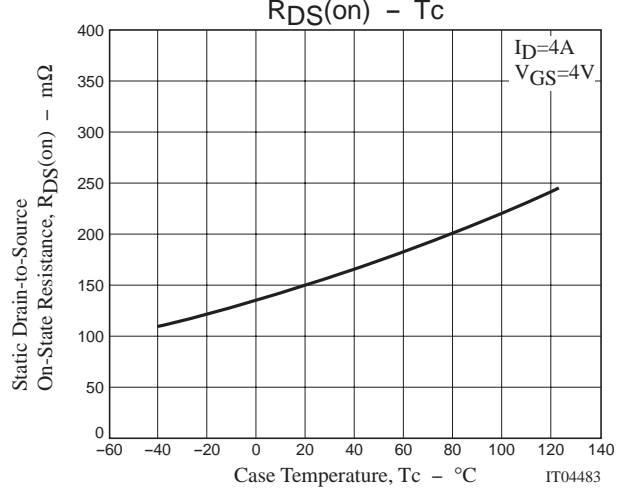
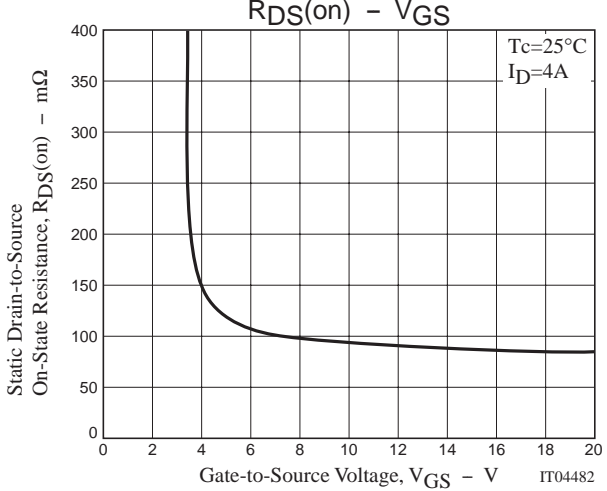
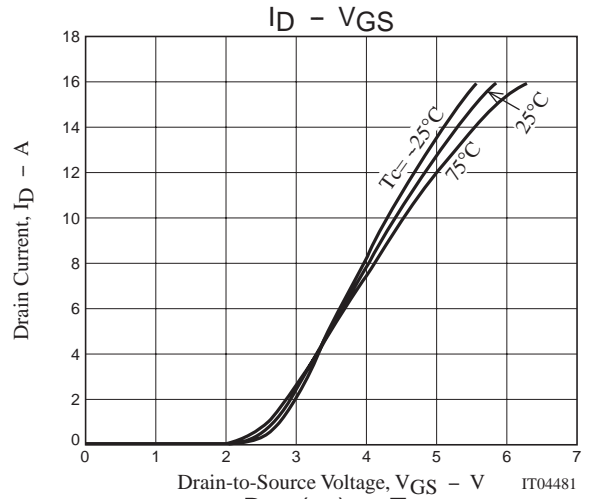
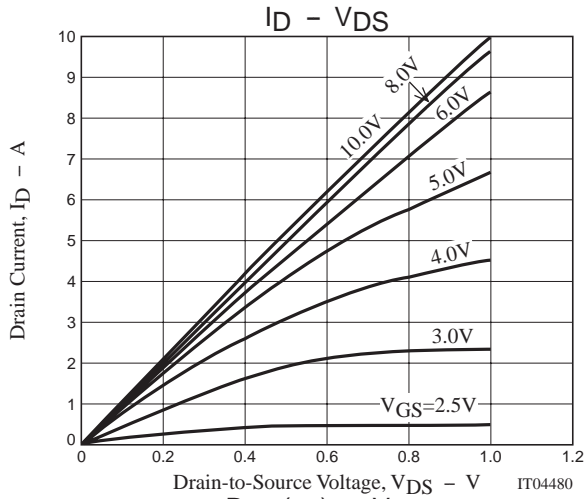
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		60	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	I _D		8	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	32	A
Allowable Power Dissipation	P _D		1	W
		T _c =25°C	15	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

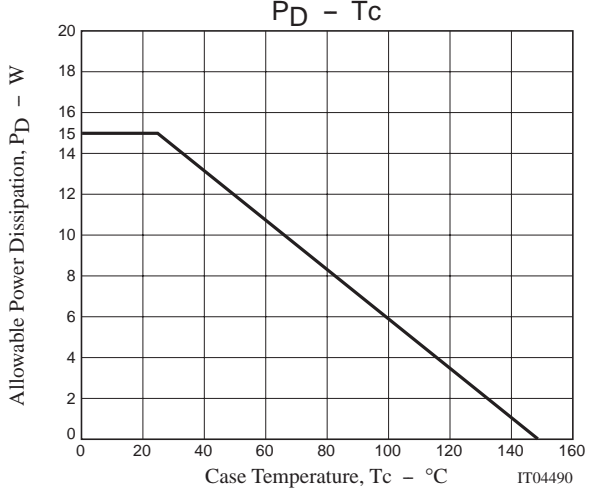
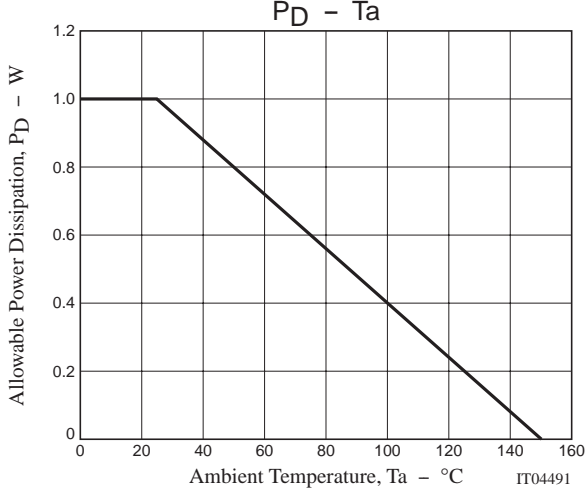
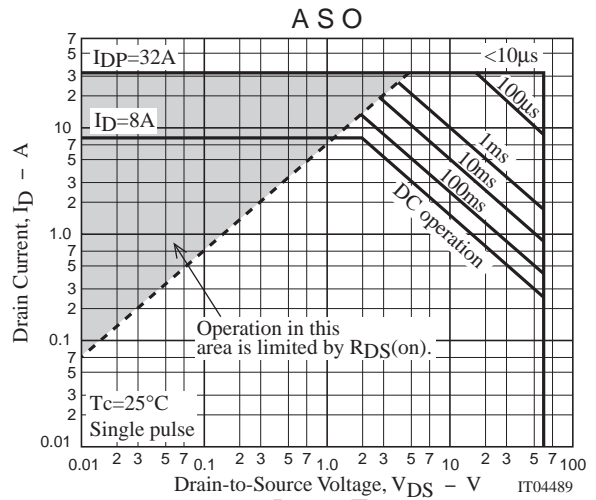
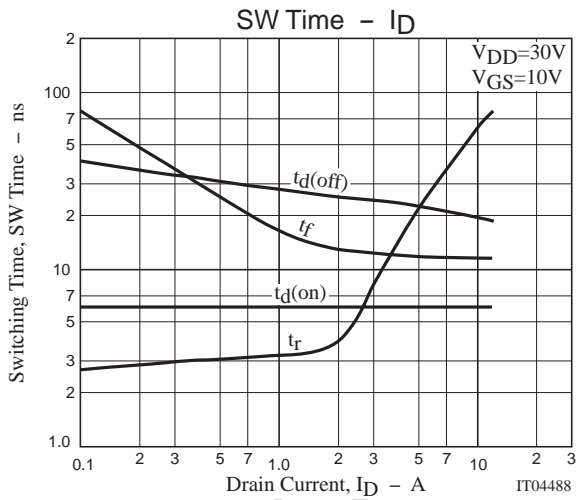
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D =1mA, V _{GS} =0	60			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0			10	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±16V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =1mA	1.0		2.4	V
Forward Transfer Admittance	y _{fs}	V _{DS} =10V, I _D =4A	3.8	5.5		S
Static Drain-to-Source On-State Resistance	R _{DS(on)}	I _D =4A, V _{GS} =10V		115	150	mΩ
	R _{DS(on)}	I _D =4A, V _{GS} =4V		150	210	mΩ
Input Capacitance	C _{iss}	V _{DS} =20V, f=1MHz		220		pF
Output Capacitance	C _{oss}	V _{DS} =20V, f=1MHz		75		pF
Reverse Transfer Capacitance	C _{rss}	V _{DS} =20V, f=1MHz		25		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit.		6		ns
Rise Time	t _r	See specified Test Circuit.		15		ns
Turn-OFF Delay Time	t _{d(off)}	See specified Test Circuit.		25		ns
Fall Time	t _f	See specified Test Circuit.		15		ns
Total Gate Charge	Q _g	V _{DS} =10V, V _{GS} =10V, I _D =8A		8		nC
Gate-to-Source Charge	Q _{gs}	V _{DS} =10V, V _{GS} =10V, I _D =8A		1.5		nC
Gate-to-Drain "Miller" Charge	Q _{gd}	V _{DS} =10V, V _{GS} =10V, I _D =8A		2		nC
Diode Forward Voltage	V _{SD}	I _S =8A, V _{GS} =0	0.95	1.2		V

Switching Time Test Circuit







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